# VS-8ETL06SHM3



**Vishay Semiconductors** 

### Ultralow V<sub>F</sub> Hyperfast Rectifier for Discontinuous Mode PFC, 8 A, FRED Pt<sup>®</sup>



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	8 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	0.81 V							
t <sub>rr</sub> typ.	60 ns							
T <sub>J</sub> max.	175 °C							
Package	D <sup>2</sup> PAK (TO-263AB)							
Circuit configuration	Single							

#### **FEATURES**

- Benchmark ultralow forward voltage drop
- · Hyperfast recovery time
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meets JESD 201 class 1 whisker test
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

State of the art, ultralow V<sub>F</sub>, soft-switching hyperfast rectifiers optimized for discontinuous (critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 160 °C	8							
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$	175	А						
Peak repetitive forward current	I <sub>FM</sub>		16							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	N				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	0.96	1.05	V				
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	0.81	0.86					
Povereo lookago ourrent	1	$V_{R} = V_{R}$ rated	-	0.05	5					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	100	μA				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	17	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_C = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt$	= 100 A/ $\mu$ s, V <sub>R</sub> = 30 V	-	60	100				
	+	$I_F = 8 A, dI_F/dt$	= 100 A/ $\mu$ s, V <sub>R</sub> = 30 V	-	150	250	ns			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	170	-	115			
		T <sub>J</sub> = 125 °C		-	250	-				
Peak recovery current		T <sub>J</sub> = 25 °C	$I_F = 8 A$	-	15	-	А			
reak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 390 V	-	20	-	~			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	1.3	-				
Theverse recovery charge	۷rr	T <sub>J</sub> = 125 °C		-	2.6	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.4	2					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	- 0.5 -			0/10				
Weight			-	2.0	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	8ETL06SH							

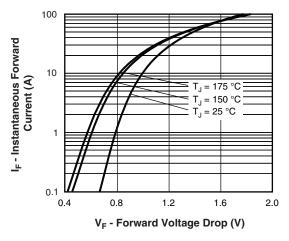


Fig. 1 - Typical Forward Voltage Drop Characteristics

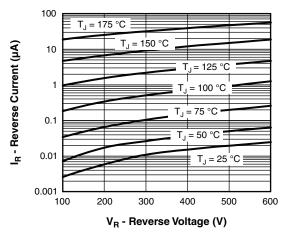


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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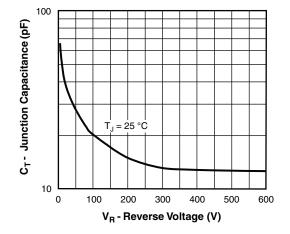


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

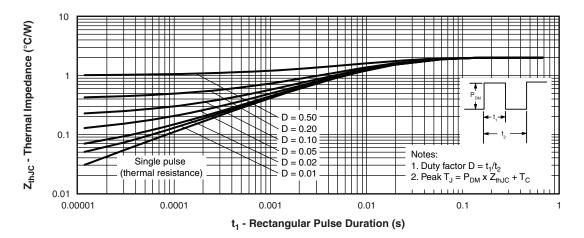
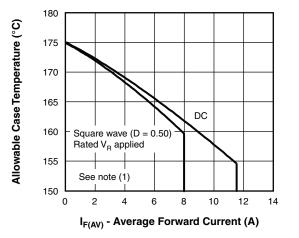
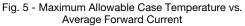


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

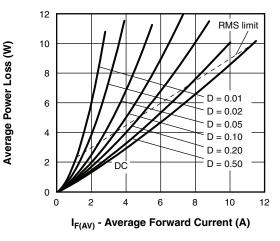


Fig. 6 - Forward Power Loss Characteristics

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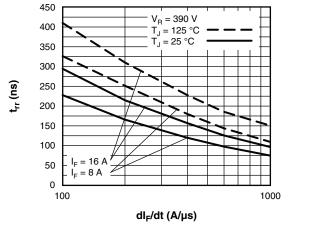


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

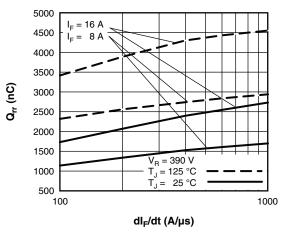


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

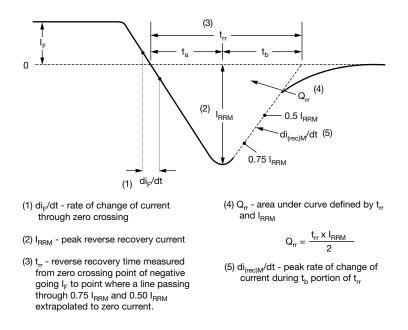


Fig. 9 - Reverse Recovery Waveform and Definitions



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#### **ORDERING INFORMATION TABLE**

Device code	VS-	8	Е	т	L	06	S	TRL	н	М3	
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)	(10)	
		Ŭ	<u> </u>	Ŭ	Ŭ		0	0	0	U	
	<u> </u>	<ol> <li>Vishay Semiconductors product</li> </ol>									
	2 -	- Current rating (8 A)									
	3 -	E =	E = single diode								
	4 -	T =	TO-220	, D <sup>2</sup> PAk	(						
	5 -	L=	ultralow	V <sub>F</sub> hype	erfast re	covery					
	6 -	Volt	age rati	ng (06 =	= 600 V)						
	7 -	• S	= D <sup>2</sup> PA	K							
	8 -	• N	one = tu	be (50 r	vieces)						
			<ul> <li>None = tube (50 pieces)</li> <li>TRL = tape and reel (left oriented, for D<sup>2</sup>PAK package)</li> </ul>								
			• TRR = tape and reel (right oriented, for D <sup>2</sup> PAK package)								
	9 -	н=	lead (P	d)-free							
	10 -	M3	= halog	en-free,	RoHS-0	complia	nt, and	terminat	tions lea	ad (Pb)-f	

ORDERING INFORMATION										
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION								
VS-8ETL06SHM3	50	Antistatic plastic tube								
VS-8ETL06STRRHM3	800	13" diameter reel								
VS-8ETL06STRLHM3	800	13" diameter reel								

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95046							
Part marking information	www.vishay.com/doc?95444							
Packaging information	www.vishay.com/doc?95032							
SPICE model	www.vishay.com/doc?96055							

## **Outline Dimensions**



D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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SHA



SYMBOL	MILLIMETERS		INC	INCHES		NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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